SCS306AH

SiC Schottky Barrier Diode

Datasheet

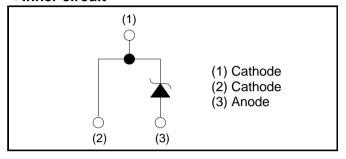
V_R	650V
I _F	6A
Q_C	19nC

Outline TO-220ACP (1) (2) (3)

Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible
- 4) High surge current capability

•Inner circuit



Packaging specifications

	Packaging	Tube
	Reel size (mm)	-
Type	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	C9
	Marking	SCS306AH

Construction

Silicon carbide epitaxial planar type

• Absolute maximum ratings $(T_i = 25^{\circ}C)$

-Absolute maxim	um ratings $(T_j = 25 \text{ C})$			
Parameter		Symbol	Value	Unit
Reverse voltage (re	epetitive peak)	V_{RM}	650	V
Reverse voltage (D	C)	V_R	650	V
Continuous forward	I current (T _c = 135°C)	I _F	6	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		47	А
repetitive forward current	PW=10ms sinusoidal, T _j =150°C	I_{FSM}	40	А
	PW=10μs square, T _j =25°C		170	А
Repetitive peak forward current		I _{FRM}	28 *1	А
1≦PW≦10ms, T _j =25°C		۲ ،2 _۱ ،	11	A ² s
i ² t value	1≦PW≦10ms, T _j =150°C	$\int i^2 dt$	8	A ² s
Total power disspation		P_{D}	46 *²	W
Junction temperature		T _j	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

•Electrical characteristics $(T_j = 25^{\circ}C)$

Parameter	Symbol	Conditions	Values			Linit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =30μA	650	-	-	V
	V _F	I _F =6A,T _j =25°C	-	1.35	1.50	V
Forward voltage		I _F =6A,T _j =150°C	-	1.44	1.71	V
		I _F =6A,T _j =175°C	-	1.50	-	V
Reverse current	I _R	V _R =650V,T _j =25°C	-	0.018	30	μΑ
		V _R =650V,T _j =150°C	-	1.2	120	μΑ
		V _R =650V,T _j =175°C	-	3.6	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	300	-	pF
		V _R =650V,f=1MHz	-	27	-	pF
Total capacitive charge	Q_{C}	V _R =400V,di/dt=350A/μs	-	19	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	15	-	ns
Non-repetetive Avaranche Energy	E _{ava}	L=1mH	1	71	-	mJ

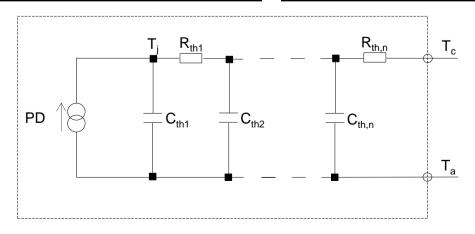
Thermal characteristics

Parameter	Symbol	Conditions -	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	$R_{\text{th(j-c)}}$	-	1	2.2	3.2	K/W

●Typical Transient Thermal Characteristics

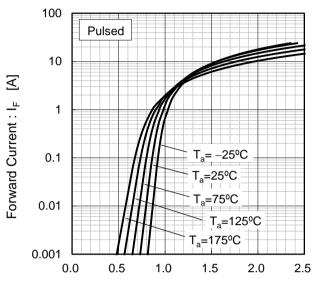
Symbol	Value	Unit
R _{th1}	3.09×10 ⁻²	
R _{th2}	3.09×10 ⁻¹	K/W
R _{th3}	1.83×10 ⁰	

Symbol	Value	Unit
C _{th1}	1.81×10 ⁻⁴	
C _{th2}	6.65×10 ⁻⁴	Ws/K
C _{th3}	1.58×10 ⁻³	



•Electrical characteristic curves

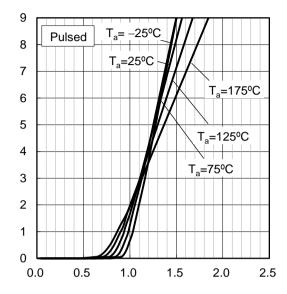
Fig.1 V_F - I_F Characteristics



Forward Voltage : V_F [V]

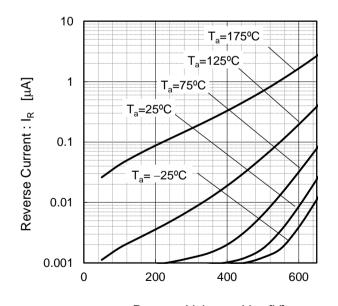
Fig.2 V_F - I_F Characteristics

Forward Current : I_F [A]



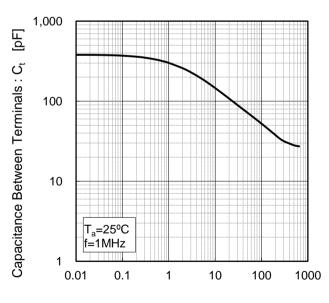
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

Fig.4 V_R-C_t Characteristics



Reverse Voltage : V_R [V]

• Electrical characteristic curves

Fig.5 Typical Transient Thermal Resistance vs. Pulse Width

10

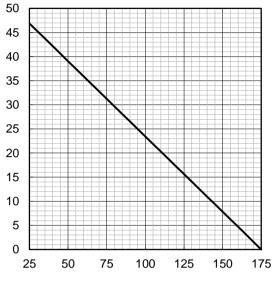
T_a=25°C
Single Pulse

0.01
0.0000001
0.001
1

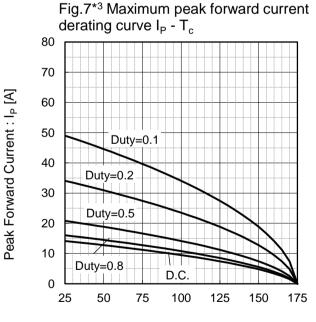
Pulse Width: P_W [s]

Fig.6 Power Dissipation

Power Dissipation [W]



Case Temperature : T_c [°C]



Case Temperature : T_c [°C]
*3 Based on max Vf, max R_{th(j-c)}
Valid for switching of above 10kHz, excluding D.C. curve.

derating curve I_P - T_c (Not guaranteed) 80 70 Duty=0.1 60 Duty=0.2 50 40 Duty=0.5 30 20 Duty=0.8 10 D.C. 0 25 50 75 100 125 150 175

Fig.8*4 Typical peak forward current

Case Temperature : T_c [°C]

*4 Based on typ Vf, typ R_{th(j-c)}
Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

Peak Forward Current: Ip [A]

Electrical characteristic curves

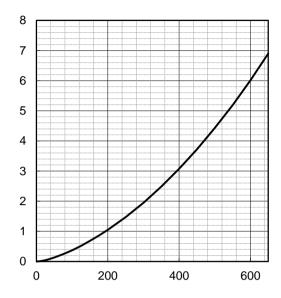
vs. Pulse width (Sinusoidal waveform) Surge non-repetitive forward current : I_{FSM} [A] 1000 100 T_a=25°C Single Pulse

Fig.9 Surge non-repetitive forward current

Pulse Width: Pw [s]

0.001

Fig.10 Typical capacitance store energy



Capacitance stored energy ։ $\mathsf{E}_\mathsf{C}[\mu J]$

0.01

Reverse Voltage: V_R [V]

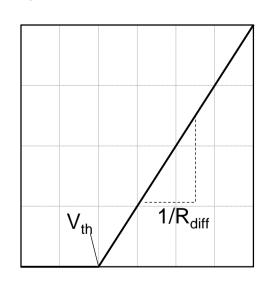
Symplified forward characteristic model

0.0001

0.00001

Forward Current: IF

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th} (T_j) = a_0 + a_1 T_j$$

 $R_{diff} (T_j) = b_0 + b_1 T_j + b_2 T_j^2$

Symbol	Typical Value	Unit
a ₀	9.66×10 ⁻¹	V
a ₁	-1.1×10 ⁻³	V/°C
b_0	5.87×10 ⁻²	Ω
b ₁	1.24×10 ⁻⁴	Ω/°C
b ₂	1.28×10 ⁻⁶	Ω/°C ²

 T_i in °C; -55 °C < T_i < 175°C; I_F < 12 A

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